

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

FCP36N60N

• FEATURES

- With TO-220 packaging
- High speed switching
- · Very high commutation ruggedness
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

• ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

APPLICATIONS

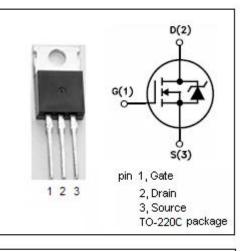
- PFC stages
- LCD & PDP TV
- Power supply
- Switching applications

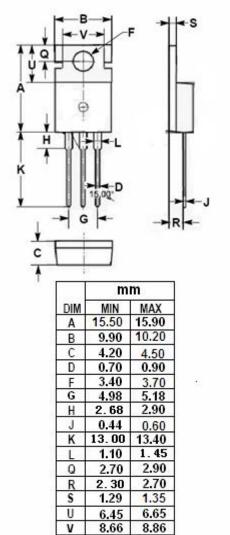
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GSS}	Gate-Source Voltage	±30	V	
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	36 22.7	А	
I _{DM}	Drain Current-Single Pulsed	108	А	
PD	Total Dissipation	312	W	
Tj	Operating Junction Temperature	-55~150	°C	
T _{stg}	Storage Temperature	-55~150	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.4	°C /W	
Rth(ch-a)	h-a) Channel-to-ambient thermal resistance		°C /W	

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isc website: www.iscsemi.cn





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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	600			V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =10V; I _D =0.25mA	2.0		4.0	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	V _{GS} = 10V; I _D =18A		81	90	mΩ
Igss	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μ Α
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 480V; V _{GS} = 0V;Tj=25℃ V _{DS} = 480V; V _{GS} = 0V;Tj=125℃			10 100	μ Α
V _{SDF}	Diode forward voltage	I _{SD} =18A, V _{GS} = 0 V			1.2	V

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